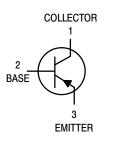
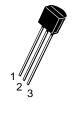
## **Amplifier Transistors**

#### **PNP Silicon**



#### http://onsemi.com





CASE 29 TO-92 STYLE 17

### MAXIMUM RATINGS

| Rating   | Symbol                            | Value             | Unit           |
|--|-----------------------------------|-------------------|----------------|
| Collector-Emitter Voltage  BC556 BC557 BC558                         | VCEO                              | -65<br>-45<br>-30 | Vdc            |
| Collector-Base Voltage  BC556 BC557 BC558                            | V <sub>СВО</sub>                  | -80<br>-50<br>-30 | Vdc            |
| Emitter-Base Voltage   | V <sub>EBO</sub>                  | -5.0              | Vdc            |
| Collector Current – Continuous<br>– Peak                             | I <sub>C</sub>                    | -100<br>-200      | mAdc           |
| Base Current – Peak  | I <sub>BM</sub>                   | -200              | mAdc           |
| Total Device Dissipation  @ T <sub>A</sub> = 25°C  Derate above 25°C | PD                                | 625<br>5.0        | mW<br>mW/°C    |
| Total Device Dissipation  @ T <sub>C</sub> = 25°C  Derate above 25°C | P <sub>D</sub>                    | 1.5<br>12         | Watts<br>mW/°C |
| Operating and Storage Junction<br>Temperature Range                  | T <sub>J</sub> , T <sub>stg</sub> | –55 to<br>+150    | °C             |

#### THERMAL CHARACTERISTICS

| Characteristic                          | Symbol         | Max  | Unit |
|---|----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 200  | °C/W |
| Thermal Resistance, Junction to Case    | $R_{	heta JC}$ | 83.3 | °C/W |

#### **ORDERING INFORMATION**

| Device    | Package | Shipping         |  |
|-----------|---------|------------------|--|
| BC556B    | TO-92   | 5000 Units/Box   |  |
| BC556BRL1 | TO-92   | 2000/Tape & Reel |  |
| BC556BZL1 | TO-92   | 2000/Ammo Pack   |  |
| BC557     | TO-92   | 5000 Units/Box   |  |
| BC557ZL1  | TO-92   | 2000/Ammo Pack   |  |
| BC557A    | TO-92   | 5000 Units/Box   |  |
| BC557AZL1 | TO-92   | 2000/Ammo Pack   |  |
| BC557B    | TO-92   | 5000 Units/Box   |  |
| BC557BRL1 | TO-92   | 2000/Tape & Reel |  |
| BC557BZL1 | TO-92   | 2000/Ammo Pack   |  |
| BC557C    | TO-92   | 5000 Units/Box   |  |
| BC557CZL1 | TO-92   | 2000/Ammo Pack   |  |
| BC558B    | TO-92   | 5000 Units/Box   |  |
| BC558BRL  | TO-92   | 2000/Tape & Reel |  |
| BC558BRL1 | TO-92   | 2000/Tape & Reel |  |
| BC558BZL1 | TO-92   | 2000/Ammo Pack   |  |
| BC558C    | TO-92   | 5000 Units/Box   |  |
| BC558CRL1 | TO-92   | 2000/Tape & Reel |  |
| BC558ZL1  | TO-92   | 2000/Ammo Pack   |  |
| BC558CZL1 | TO-92   | 2000/Ammo Pack   |  |

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   |       | Symbol   | Min             | Тур  | Max  | Unit |
|--|-------|----------|-----------------|------|------|------|
| OFF CHARACTERISTICS                                    |       |          |                 |      |      |      |
| Collector–Emitter Breakdown Voltage                    |       | V(BR)CEO |                 |      |      | V    |
| $(I_C = -2.0 \text{ mAdc}, I_B = 0)$                   | BC556 |          | -65             | _    | -    |      |
|  | BC557 |          | <del>-4</del> 5 | _    | _    |      |
|  | BC558 |          | -30             | _    | _    |      |
| Collector-Base Breakdown Voltage                       |       | V(BR)CBO |                 |      |      | V    |
| $(I_C = -100 \mu\text{Adc})$                           | BC556 | (511)050 | -80             | _    | _    |      |
|  | BC557 |          | -50             | _    | _    |      |
|  | BC558 |          | -30             | _    | _    |      |
| Emitter-Base Breakdown Voltage                         |       | V(BR)EBO |                 |      |      | V    |
| $(I_F = -100  \mu Adc, I_C = 0)$                       | BC556 | (511)250 | -5.0            | _    | _    |      |
|  | BC557 |          | -5.0            | _    | -    |      |
|  | BC558 |          | -5.0            | _    | -    |      |
| Collector–Emitter Leakage Current                      |       | ICES     |                 |      |      |      |
| (VCFS = -40 V)   | BC556 | 020      | _               | -2.0 | -100 | nA   |
| (VCES = -20 V)   | BC557 |          | _               | -2.0 | -100 |      |
|  | BC558 |          | -               | -2.0 | -100 |      |
| $(V_{CES} = -20 \text{ V}, T_A = 125^{\circ}\text{C})$ | BC556 |          | _               | _    | -4.0 | μΑ   |
|  | BC557 |          | -               | _    | -4.0 |      |
|  | BC558 |          | _               | _    | -4.0 |      |

#### $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{\mbox{\scriptsize A}} = 25^{\circ}\mbox{C unless otherwise noted})$

| Characteristic  |                         | Symbol               | Min   | Тур    | Max   | Unit |
|---|-------------------------|----------------------|-------|--------|-------|------|
| ON CHARACTERISTICS  |                         |                      |       |        |       |      |
| DC Current Gain   |                         | hFE                  |       |        |       | _    |
| $(I_C = -10 \mu\text{Adc}, V_{CE} = -5.0 \text{V})$                                 | A Series Device         | '-                   | _     | 90     | _     |      |
| , ,   | B Series Devices        |                      | _     | 150    | _     |      |
|   | C Series Devices        |                      | _     | 270    | _     |      |
| $(I_C = -2.0 \text{ mAdc}, V_{CF} = -5.0 \text{ V})$                                | BC557                   |                      | 120   | _      | 800   |      |
| , <u> </u>  | A Series Device         |                      | 120   | 170    | 220   |      |
|   | <b>B</b> Series Devices |                      | 180   | 290    | 460   |      |
|   | C Series Devices        |                      | 420   | 500    | 800   |      |
| $(I_C = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ V})$                                | A Series Device         |                      | _     | 120    | _     |      |
| <b>3</b> 2  | B Series Devices        |                      | _     | 180    | _     |      |
|   | C Series Devices        |                      | -     | 300    | _     |      |
| Collector–Emitter Saturation Voltage  |                         | VCE(sat)             |       |        |       | V    |
| $(I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc})$                                 |                         | 0 = (0 0 0 0)        | _     | -0.075 | -0.3  |      |
| $(I_C = -10 \text{ mAdc}, I_B = \text{see Note 1})$                                 |                         |                      | _     | -0.3   | -0.6  |      |
| $(I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$                                |                         |                      | _     | -0.25  | -0.65 |      |
| Base–Emitter Saturation Voltage   |                         | V <sub>BE(sat)</sub> |       |        |       | V    |
| $(I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc})$                                 |                         | (==,                 | _     | -0.7   | _     |      |
| $(I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$                                |                         |                      | -     | -1.0   | -     |      |
| Base–Emitter On Voltage   |                         | VBE(on)              |       |        |       | V    |
| $(I_C = -2.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$                              |                         | (- /                 | -0.55 | -0.62  | -0.7  |      |
| $(I_C = -10 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$                               |                         |                      | -     | -0.7   | -0.82 |      |
| SMALL-SIGNAL CHARACTERISTICS  |                         |                      |       |        |       |      |
| Current-Gain - Bandwidth Product  |                         | fT                   |       |        |       | MHz  |
| $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}, f = 100 \text{ MHz})$              | BC556                   |                      | _     | 280    | _     |      |
|   | BC557                   |                      | _     | 320    | _     |      |
|   | BC558                   |                      | -     | 360    | -     |      |
| Output Capacitance  |                         | C <sub>ob</sub>      | -     | 3.0    | 6.0   | рF   |
| $(V_{CB} = -10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$                          |                         |                      |       |        |       |      |
| Noise Figure  |                         | NF                   |       |        |       | dB   |
| $(I_C = -0.2 \text{ mAdc}, V_{CE} = -5.0 \text{ V},$                                | BC556                   |                      | -     | 2.0    | 10    |      |
| $R_S = 2.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ , $\Delta f = 200 \text{ Hz}$ ) | BC557                   |                      | -     | 2.0    | 10    |      |
|   | BC558                   |                      | -     | 2.0    | 10    |      |
| Small-Signal Current Gain   |                         | h <sub>fe</sub>      |       |        |       | _    |
| $(I_C = -2.0 \text{ mAdc}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz})$            | BC557                   |                      | 125   | -      | 900   |      |
|   | A Series Device         |                      | 125   | -      | 260   |      |
|   | B Series Devices        |                      | 240   | -      | 500   |      |
|   | C Series Devices        |                      | 450   |        | 900   |      |

#### BC557/BC558

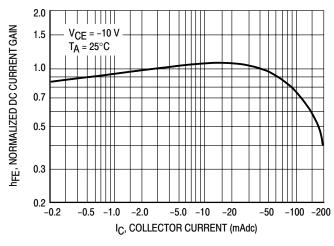


Figure 1. Normalized DC Current Gain

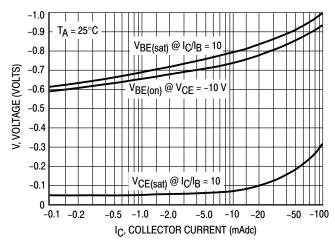


Figure 2. "Saturation" and "On" Voltages

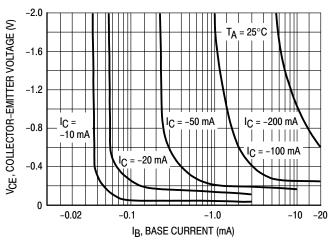


Figure 3. Collector Saturation Region

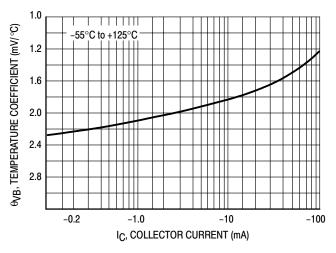


Figure 4. Base-Emitter Temperature Coefficient

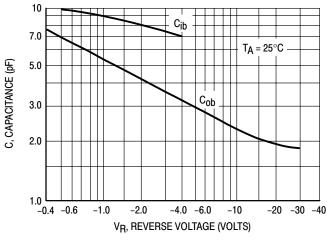


Figure 5. Capacitances

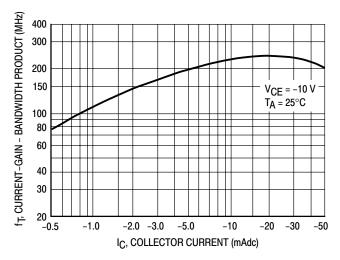


Figure 6. Current-Gain - Bandwidth Product

#### **BC556**

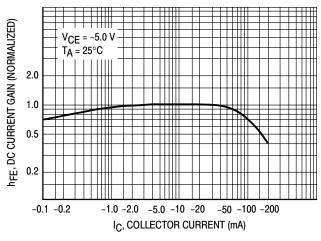


Figure 7. DC Current Gain

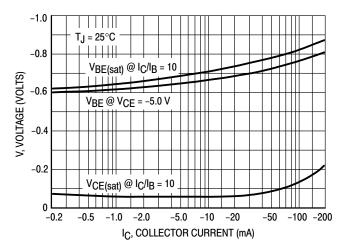


Figure 8. "On" Voltage

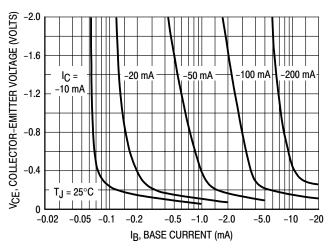


Figure 9. Collector Saturation Region

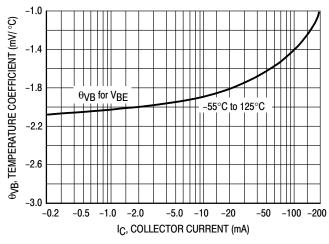


Figure 10. Base-Emitter Temperature Coefficient

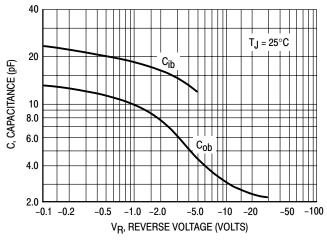


Figure 11. Capacitance

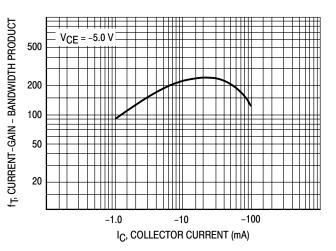


Figure 12. Current-Gain - Bandwidth Product

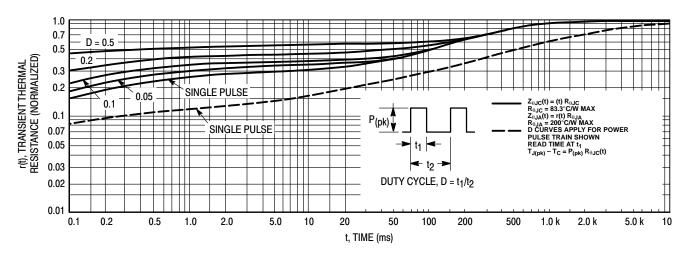


Figure 13. Thermal Response

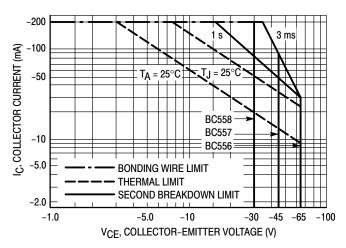


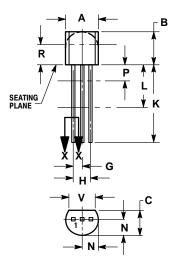
Figure 14. Active Region – Safe Operating Area

The safe operating area curves indicate I<sub>C</sub>–V<sub>CE</sub> limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^{\circ}\text{C}$ ;  $T_{C}$  or  $T_{A}$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^{\circ}\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

#### **PACKAGE DIMENSIONS**

TO-92 (TO-226) CASE 29-11 **ISSUE AL** 





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| С   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.021 | 0.407  | 0.533  |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| P   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| v   | 0 135  |       | 3 43   |        |

- STYLE 17:
  PIN 1. COLLECTOR
  2. BASE
  3. EMITTER

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